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### SIMULTANEOUS DIFFRACTION IN ANTHRACENE\*

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### ABSTRACT

An analytical method is used to index the (100) simultaneous diffractions in (monoclinic) anthracene. The expected pattern of diffractions is calculated and compared with experimental observations. The computations are amenable to desk calculators. Simultaneous diffractions from 23 different pairs of planes have been identified and tabulated for anthracene using Cu Koradiation.

### INTRODUCTION

Recently there appeared in the literature a graphical method of indexing simultaneous diffractions, with an extensive discussion of the (222) pattern of germanium (Cole, et al, 1962). An alternative, although equivalent, analytical method has been in use for several years at this laboratory (Alexander, et al, 1959). This method is capable of predicting the pattern of the expected simultaneous diffractions for a particular case and is amenable to computations on a desk calculator. It will be described in detail for the case of the (100) Cu K& pattern of (monoclinic) anthracene.

To produce the  $(h_r k_r k_r)$  simultaneous diffractions the crystal is rotated about  $\underline{h}(r)$ , the reciprocal lattice vector of the  $(h_r k_r k_r)$  planes, and the X-ray beam is incident at the Bragg angle appropriate for these planes. As the crystal rotates there are certain positions in which the Bragg condition will be satisfied as well for another set of planes  $(h_s k_s k_s)$ . These positions occur whenever the incoming beam is directed along an intersection of the Kossel cones about the vectors  $\underline{h}(r)$  and  $\underline{h}(s)$ , where  $\underline{h}(s)$  is the reciprocal lattice vector of the  $(h_s k_s k_s)$  planes. The direction of the beam for this position is  $\underline{S}_{rs}$  (Figure 1). In this case both  $\underline{h}(r)$  and  $\underline{h}(s)$  vectors lie on the Ewald sphere in reciprocal space, and as is well known (Laue, 1960), simultaneous diffraction occurs, involving the  $(h_s k_s k_s)$  and  $(h_t k_t k_t)$  planes. These planes will be referred to as the "operative" (or "first") and the "cooperative" (or "second") planes, respectively (Cole, et al, 1962). The relation among the indices of these planes is found to be (Renninger, 1937; Laue, 1960; James, 1958):

(1) 
$$h_r = h_s + h_t$$
,  $k_r = k_s + k_t$ ,  $\ell_r = \ell_s + \ell_t$ .

<sup>\*</sup> The existence of a (100) multiple diffraction in anthracene was first mentioned in the Ph. D. thesis of one of us (B.S.F.), Jerusalem, 1954. The "forbidden" (100) reflection was seen on a Weissenberg photograph about the b-axis with Cu Kx radiation.

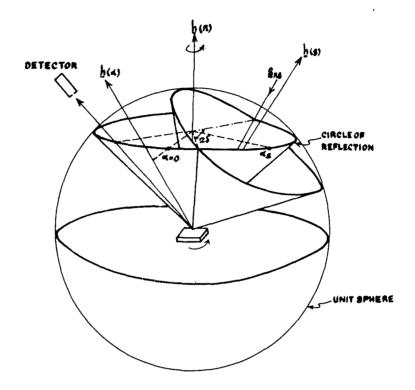


Figure 1. The unit sphere showing the Kossel cones of the  $(h_r k_r \ell_r)$  and the  $(h_s k_s \ell_s)$  planes. The crystal rotates about  $\underline{h}(r)$ , the reciprocal lattice vector of the  $(h_r k_r \ell_r)$  planes. The angular separation of the intersections of the cones, measured along the circle of reflection, is  $2\gamma$ . An arbitrary vector  $\underline{h}(\alpha)$  determines the reference point  $\alpha = 0$ , as described in the text. The beam enters at the Bragg angle for the  $(h_r k_r \ell_r)$  planes. Simultaneous diffraction occurs when the beam enters in the  $\underline{S}_{rs}$  direction, along an intersection of the two cones, and is detected as a peak above the background.

The same relationship holds when the roles of  $(h_s k_s l_s)$  and  $(h_t k_t l_t)$  are interchanged.

Our object then is to find all the real intersections between the fixed cone about  $\underline{h}(r)$  and the cones about any other vectors  $\underline{h}(s)$ . Consider the circle of reflection,  $\underline{i.e.}$ , the intersection of the Kossel cone about  $\underline{h}(r)$  and the unit sphere (Figure 1). The cone about  $\underline{h}(s)$  will in general have two intersections with the  $\underline{h}(r)$  cone. Let the angular separation of these two "equivalent" intersections, measured along the circle of reflection, be called  $2\gamma$ . This information alone is insufficient to identify unequivocally the reflections of an observed pattern. The pattern of simultaneous diffractions can be predicted if, in addition to knowing  $2\gamma$ , the mid-points of all possible pairs of equivalent reflections are related to the same arbitrary reference point. Accordingly let us define  $\alpha$  as the angular separation on the circle of reflection between an arbitrary reference point and the mid-point, along the circle, of two equivalent intersections. The  $\alpha$  = 0 reference point is determined by the intersection of the reflection circle with the plane containing h(r) and h(x), an arbitrary vector.

In practice, it is possible to observe the simultaneous diffractions if the  $(h_r k_r l_r)$  reflection is weak, or forbidden, and those of  $(h_s k_s l_s)$  and  $(h_t k_t l_t)$  are strong. The  $(h_s k_s l_s)$ ,  $h_t k_t l_t$  simultaneous diffractions are then seen as peaks above the  $(h_r k_r l_r)$  background (Figures 2 and 3).

### Theory

The conditions to be met by the incoming beam when the crystal is simultaneously diffracting are (Laue, 1960)

(2) 
$$\begin{cases} \underline{S}_{rs}^{2} = 1 \\ \underline{2h(r)} \cdot \underline{S}_{rs} = -\lambda \underline{h(r)}^{2} \\ \underline{2h(s)} \cdot \underline{S}_{rs} = -\lambda \underline{h(s)}^{2} . \end{cases}$$

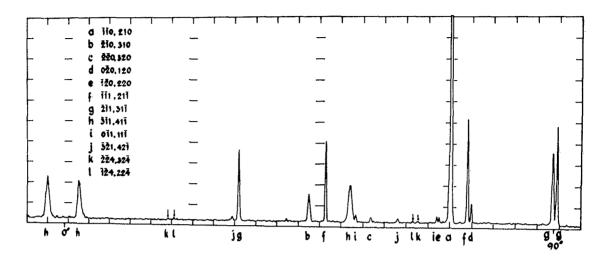


Figure 2. Counter record of the anthracene (100) simultaneous diffraction pattern for Cu Kα radiation, monochromatized by LiF. Full scale, 2000 counts per second; time constant, one second; chart speed, one inch per minute; crystal rotated at 92 minutes per revolution; x-ray tupe operated at 40 kV, 20 mA.



Figure 3. Photographic record of the anthracene (1 00) simultaneous diffraction pattern for monochromatic Cu Kα radiation. Crystal rotated at 92. minutes per revolution; x-ray tube operated at 40 kV, 20 mA; 50-hour exposure.

It can be seen from geometrical considerations (Alexander, et al, 1959) that

(3) 
$$\cos \Upsilon = \frac{\left[S_{rs} \times h(r)\right] \cdot \left[h(s) \times h(r)\right]}{\left[S_{rs} \times h(r)\right] \cdot \left[h(s) \times h(r)\right]},$$

where both the positive and negative values of  $\Upsilon$  are solutions. Combining equations (2) and (3)

(4) 
$$\cos \mathcal{Z} = \frac{\frac{h(\mathbf{r}) \left[\underline{\mathbf{h}}(\mathbf{r}) \cdot \underline{\mathbf{h}}(\mathbf{s}) - \underline{\mathbf{h}}(\mathbf{s})^{2}\right]}{\sqrt{4 - \frac{2}{h}(\mathbf{r})^{2}} \left[\underline{\mathbf{h}}(\mathbf{s}) \times \underline{\mathbf{h}}(\mathbf{r})\right]}}.$$

(5) 
$$\cos \alpha = \frac{\left[\underline{\mathbf{h}}(\mathbf{r}) \times \underline{\mathbf{h}} \times \underline{\mathbf{h}} \times \underline{\mathbf{h}}(\alpha)\right] \cdot \left[\underline{\mathbf{h}}(\mathbf{r}) \times \underline{\mathbf{h}}(\mathbf{s})\right]}{\left[\underline{\mathbf{h}}(\mathbf{r}) \times \underline{\mathbf{h}}(\mathbf{s})\right]} \cdot$$

In addition, an expression for  $\sin \alpha$  is necessary in order to determine  $\alpha$  unambiguously. It is convenient to choose a vector of length  $\sin \alpha$  as follows:

(6) 
$$\frac{\underline{h}(r)}{|\underline{h}(r)|} \sin \alpha = \frac{[\underline{h}(r) \times \underline{h}(\alpha)] \times [\underline{h}(r) \times \underline{h}(s)]}{|\underline{h}(r) \times \underline{h}(\alpha)| |\underline{h}(r) \times \underline{h}(s)|}.$$

This vector is either parallel or antiparallel to  $\underline{h}(r)$ , depending on the sign of  $\sin \alpha$ .

### Anthracene (100) simultaneous diffractions

The (100) reflection in anthracene has a zero structure factor (Mathieson, et al, 1950), therefore simultaneous diffraction peaks are expected. Thus, let  $(h_r k_r l_r)$  be (100), and (hkl) be the operative  $(h_s k_s l_s)$  planes. Expressing equation (4) in terms of the monoclinic lattice constants a, b, c, and  $\beta$  we get

(7) 
$$\cos \mathcal{J}_{100} = \frac{b^2 c^2 h(1-h) - \partial^2 c^2 k^2 \sin^2 \beta - a^2 b^2 l^2 + l(2h-1)acb^2 \cos \beta}{\partial^2 bc \sin^2 \beta \sqrt{4\lambda^{-2} - (a \sin \beta)^{-2}} \sqrt{c^2 k^2 + b^2 l^2}}.$$

Using the anthracene data given by Mathieson, et al, (1956), the expression for  $\chi_{100}$  becomes for Cu Ka radiation

(8) 
$$\cos \chi_{100} = \frac{(0.0232352)[4.54004 \text{ h}(1-\text{h})-6.17308\text{k}^2-2.67022]\ell^2-1.98212\ell(2\text{h}-1)]}{\sqrt{1.24613\text{k}^2+0.364333}\ell^2}$$

For the reference  $\not = 0$ , the reciprocal lattice vector of the (010) planes is a convenient choice for h(x). Equation (5) becomes

(9) 
$$\cos \alpha = \frac{k}{\sqrt{k^2 + (\frac{b}{c})^2 \ell^2}} = \frac{k}{\sqrt{k^2 + 0.29237 \ell^2}}$$

Similarly, equation (6) gives

(10) 
$$\sin \alpha = \frac{\ell}{\sqrt{\ell^2 + (\frac{c}{b})^2 k^2}} = \frac{\ell}{\sqrt{\ell^2 + 3.4203k^2}}$$

The positive square roots are used throughout.

Consider now a particular set of planes  $(h_s k_s l_s)$  operative. Equations (9) and (10) yield a single value  $\alpha_s$  for these indices; equation (8) gives us  $\gamma_s$ . Hence, there will be two reflections for this case, at  $\alpha_s + \gamma_s$ . Alternatively consider the  $(h_t k_t l_t)$  planes operative. By equation (1) these can be re-expressed as  $(1-h_s, R_s, \tilde{l}_s)$  when  $(h_k k_t l_t)$  is (100). The same value  $\gamma_s$  results, as expected, whereas  $\alpha_t = \alpha_s + \pi$ . Thus for  $(h_t k_t l_t)$  operative, two more reflections are obtained, at  $\pi + \alpha_s + \gamma_s$ . Similarly, the  $(h_s R_s l_s)$  planes lead to two reflections, at  $\pi - \alpha_s + \gamma_s$ ; the  $(h_t R_t l_t)$  or  $(1-h_s, k_s, \tilde{l}_s)$  planes also give two, at  $-\alpha_s + \gamma_s$  (with the same numerical values of  $\gamma_s$  and  $\alpha_s$  throughout).

Thus for the anthracene (100) case each pair of planes  $(h_s k_s \ell_s, h_t k_t \ell_t)$  satisfying equation (1) gives rise to four reflections, two from each set of planes considered in turn as operative. Four more reflections arise from the symmetrically related pair of planes  $(h_s k_s \ell_s, h_t k_t \ell_t)$ . If the incoming beam is unpolarized these four pairs of reflections are of equal intensity. (For a polarized beam this is in general not true). Therefore, eight reflections appear, in general, at  $\pm \alpha_s \pm \gamma_s$  and  $\pi \pm \alpha_s \pm \gamma_s$ .

If  $\alpha$  is 0, or  $\mathbb{T}$ , as it is if the pair of planes is of the type  $(h_s k_s 0, h_t k_t 0)$ , only four reflections appear. Since  $\alpha$  is independent of h, different pairs of planes with different values of h, but the same values of k and  $\ell$ , show a symmetrical distribution about the same points  $+\alpha$ , and  $\mathbb{T}+\alpha$ .

The convenience of  $\underline{h}(010)$  as  $\underline{h}(d)$  results from the symmetry properties it has for the (100) simultaneous diffraction case. (An alternative and equally convenient choice for  $\underline{h}(d)$  would be  $\underline{h}(001)$ ). Had  $\underline{h}(d)$  been chosen less conveniently, the expressions for  $\cos d$  and  $\sin d$  would have been somewhat more complicated.

When one considers the (100) anthracene case, one is struck by the large number of possible combinations of planes which satisfy equation (1). There are over a thousand possibilities of simultaneous diffractions in the (100) case for Cu Ka, as can easily be seen from the list of planes whose structure factors are reported by Mathieson, et al, (1950). Many of these pairs are forbidden because by equation (8)  $\cos \chi > 1$ . Most, however, are pairs of planes with small structure factors which contribute in an undetermined way to the background. In practice we have observed about 76 peaks standing out from a more-or-less homogeneous background. These reflections are labelled a to  $\ell$  in Figure 2. Many other possible but weak reflections can be made out along the recorder chart, distinguishable from the background only by careful comparison of several runs over the same or equivalent range. These are not marked on the chart, but are included in Table 1. Due to the symmetrical distribution of reflections only a  $\pi/2$  range need be examined at a time.

To minimize the amount of calculation necessary to effect the complete identification, we chose only those possible pairs of planes whose products of structure factors are larger than 200. There are 26 different pairs of planes, and they are sufficient to account for all observed peaks. That this procedure is justified can be seen from the table. The strongest reflections observed did indeed originate from pairs of planes with large structure factors. Had complete identification been impossible using this first selection, the calculation would have been extended to those planes whose products of structure factors are, say, between 150 and 200, and so on, until all observations were accounted for. Any remaining ambiguities, due possibly to overlapping reflections, can often be resolved by changing the wavelength used, and hence changing the appearance of the pattern. Conversion of the set of cos and lequation (4). The value of of is independent of the wave length.

We found the commercially available anthracene crystals of scintillation grade to be inadequate for our purpose; only a few reflections were observed (those labelled a, g, f, h), and these were observed on the film as clusters of spots, making difficult the identification of any weak, closely situated reflections. To obtain better crystals we dissolved purified anthracene in alcohol and set the container in a place free from vibrations for several weeks. As the alcohol evaporated, the anthracene crystallized out of solution. Most of the crystals thus obtained were thin irregular hexagons, several tenths of a millimeter in diameter, several hundreds of a millimeter in thickness. Occasionally crystals grew that were thicker than most, although no larger in diameter. More reflections were seen in these than in the thin samples. There was considerable advantage in using counter rather than film techniques. The extremely weak reflections were not observed on the films; on the recorder charts, the weakest reflections had peaks about 5-10 cps above a background of about 30 + 5 cps, still discernable. See Figures 2 and 3. The tabulated reflections labelled m to x are of this weak intensity, and only by comparing with other runs was it possible to verify their presence. With any slight misorientation of the crystal they disappear. For

instance, reflections  $m(\bar{2}\bar{1}5, 31\bar{5})$  appear in Figure 2 at  $\pm$  1.13°, and at  $\pm$  41.73°. The former can be seen in the structure between reflections h on either side of the zero mark on the chart; the latter, at 41.73°, is the small pip about one third the way between h and g, near the center of the chart. This illustration is typical of very weak reflections.

A General Electric XRD-3 source was used, operated at 40 kV, 20 mA. The beam was monochromatized by reflection from lithium fluoride. A General Electric No. 3 detector unit was employed with the Geiger-tube and preamplifier interchangable with the film holder of the multiple diffraction spectrometer (Fraenkel, 1958).

### Acknowledgement

We are grateful to Prof. E. Alexander for many helpful discussions during the course of this work.

Table 1 (100) Simultaneous Diffractions in Anthracene with Cu K≪ radiation.

	Planes	$\begin{array}{c} {\rm Measured}^* \\ {\rm (F}_1 {\rm F}_2)^2 \end{array}$	Measured Peak Inten.	8	d	Predicted Positions in first quadrant	
a	(110,210)	$7728 \times 10^3$	3100 cps	71.48	0.0.0	71.480	71.48
g	( <b>2</b> 11,311)	1625	760	61.37	28.40	89.77	32.97
f	(111,211)	1210	870	77.33	28.40	48.93	74.27
h	(311,411)	1088	370	25.13	28.40	3.27	53.53
b	$(\overline{21}0,310)$	370	260	45.93	0.0	45.93	45.93
	$(\overline{42}1,52\overline{1})$	308		**	15.13	<b>∺</b> 5 5 5 5	
j	$(\overline{32}1,42\overline{1})$	264	43	46.93	15.13	31.80	62.06
d	(020,120)	216	170	75.11	0.0	75.11	75.11
С	$(\overline{22}0,320)$	135	50	57.28	0.0	57.28	57.28
	(521,621)	128	W & Cs	**	15.13	97699	
m	$(\overline{21}5,315)$	116	20	68.57	69.70	1.13	41.73
=0	$(\overline{31}0,410)$	110		**	0.0	-0600	
1	$(\overline{12}4,22\overline{4})$	103	20	68.13	47.24	20.89	64.63
n	(0]5,115)	97	16	62.93	69.70	6.77	47.37
i	(011,111)	83	63	82.78	28.40	54,38	68.82
r	(031,131)	73	10	67.42	10.22	57 <b>.</b> 20≠	77.64
е	(120,220)	72	50	69.42	0.0	69,42	69.42
p	(035,135)	70	16	47.03	42.02	5.01	89.05 <i>+</i>
q	$(\overline{31}5,415)$	69	16	65,22	69.70	4.48	45.08
t	(T <b>T</b> 5,215)	66	<10	67.82	69.70	1.88	42.48
k	(224,324)	64	16	67.13	47,24	19.89	65.63
s	(014,114)	63	10	69.03	65.19	3.84	45.78//
u	(024,124)	59	12	65.15	47,24	17.91	67.61
v	$(\overline{31}4,41\overline{4})$	55	<10	65.28	65.19	0.09	49.53
w	(344,444)	54	10	49.98	28.40	21.58	78.38
x	(219,319)	51	<b>≪</b> 10	47.74	78.38	30.64 <i>‡</i> ‡	53.88
	(411,511)	39	(5 th) w	3/c 3/c	28.40	***************************************	ner tar tar age me

<sup>\*\*</sup> $\cos \forall$  > 1 / overlap g / overlaps c // overlaps b // unobserved \*Mathieson, et al, (1950).

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